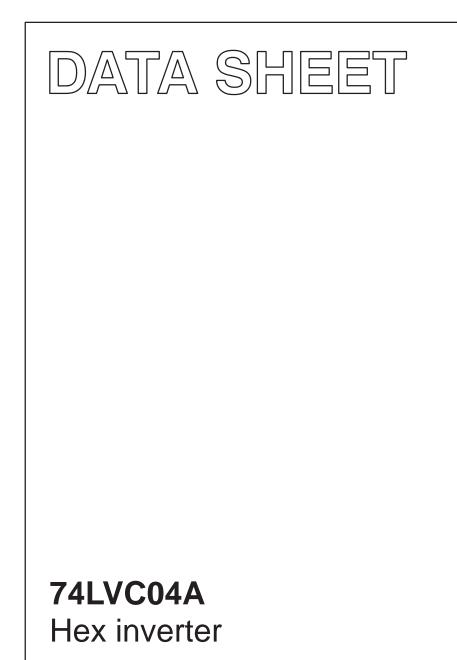
# INTEGRATED CIRCUITS



Product specification Supersedes data of 1997 Mar 28 IC24 Data Handbook 1997 Jun 30



# 74LVC04A

#### **FEATURES**

- Wide supply range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A
- Inputs accept voltages up to 5.5V
- CMOS low power consumption
- Direct interface with TTL levels
- 5-volt tolerant inputs, for interfacing with 5-volt logic

### QUICK REFERENCE DATA

#### GND = 0 V: $T_{amb} = 25^{\circ}C$ : $t_r = t_f \le 2.5$ ns

#### DESCRIPTION

The 74LVC04A is a high-performance, low-power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 V/5 V environment.

The 74LVC04A provides six inverting buffers.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay nA to nY	$C_{L} = 50 \text{ pF};$ $V_{CC} = 3.3 \text{ V}$	2.5	ns
Cl	Input capacitance		5.0	pF
C <sub>PD</sub>	Power dissipation capacitance per gate	Notes 1 and 2	25	pF

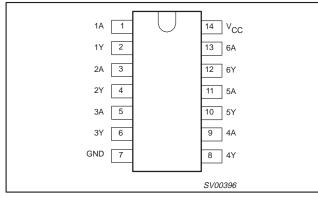
#### NOTES:

1.  $C_{PD}$  is used to determine the dynamic power dissipation (P\_D in  $\mu W)$ 1. C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in P<sub>D</sub> = C<sub>PD</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>i</sub> +  $\sum$  (C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) where: f<sub>i</sub> = input frequency in MHz; C<sub>L</sub> = output load capacity in pF; f<sub>o</sub> = output frequency in MHz; V<sub>CC</sub> = supply voltage in V;  $\sum$  (C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) = sum of the outputs. 2. The condition is V<sub>I</sub> = GND to V<sub>CC</sub>.

#### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	-40°C to +85°C	74LVC04A D	74LVC04A D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +85°C	74LVC04A DB	74LVC04A DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC04A PW	74LVC04APW DH	SOT402-1

#### **PIN CONFIGURATION**

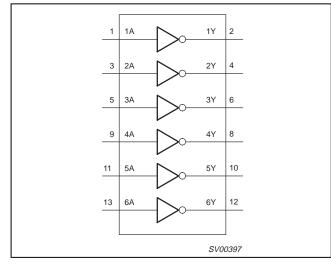


#### **PIN DESCRIPTION**

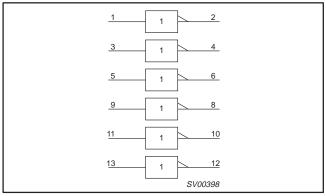
PIN NUMBER SYMBOL		NAME AND FUNCTION
1, 3, 5, 9, 11, 13	1A to 6A	Data inputs
2, 4, 6, 8, 10, 12	1Y to 6Y	Data outputs
7	GND	Ground (0 V)
14	V <sub>CC</sub>	Positive supply voltage

# 74LVC04A

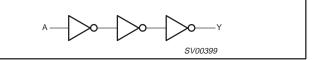
### LOGIC SYMBOL



## LOGIC SYMBOL (IEEE/IEC)



### LOGIC DIAGRAM (ONE GATE)



### **FUNCTION TABLE**

INPUTS	OUTPUTS
nA	nY
L	Н
н	L

NOTES:

H = HIGH voltage level L = LOW voltage level

# 74LVC04A

### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT	
STWBOL	FARAIVIETER	CONDITIONS	MIN	MAX	UNIT
V <sub>CC</sub>	DC supply voltage (for max. speed performance)		2.7	3.6	V
V <sub>CC</sub>	DC supply voltage (for low-voltage applications)		1.2	3.6	V
VI	DC Input voltage range		0	5.5	V
Vo	DC output voltage range		0	V <sub>CC</sub>	V
T <sub>amb</sub>	Operating ambient temperature range in free-air		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7 \text{V}$ $V_{CC} = 2.7 \text{ to } 3.6 \text{V}$	0 0	20 10	ns/V

#### ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +6.5	V
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-50	mA
VI	DC input voltage	Note 2	-0.5 to +5.5	V
I <sub>OK</sub>	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	± 50	mA
V <sub>O</sub>	DC output voltage	Note 2	V <sub>CC</sub> + 0.5	V
Ι <sub>Ο</sub>	DC output source or sink current	$V_{O} = 0$ to $V_{CC}$	±50	mA
I <sub>GND</sub> , I <sub>CC</sub>	DC V <sub>CC</sub> or GND current		±100	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
P <sub>TOT</sub>	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### Product specification

# 74LVC04A

#### DC CHARACTERISTICS

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

			L	LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -	Temp = -40°C to +85°C			
			MIN	TYP <sup>1</sup>	МАХ		
		$V_{CC} = 1.2V$	V <sub>CC</sub>			V	
V <sub>IH</sub> HIGH level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V	2.0			] `		
V <sub>IL</sub> LOW level Input voltage		$V_{CC} = 1.2V$			GND	v	
		V <sub>CC</sub> = 2.7 to 3.6V			0.8		
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12mA$	V <sub>CC</sub> -0.5				
V <sub>OH</sub>	HIGH level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100 \mu A$	V <sub>CC</sub> -0.2	V <sub>CC</sub>			
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -18\text{mA}$	V <sub>CC</sub> -0.6			V I	
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -24mA$	V <sub>CC</sub> -0.8			1	
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 12mA$			0.40		
V <sub>OL</sub>	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$			0.20	V	
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 24\text{mA}$			0.55	1	
t	Input leakage current	$V_{CC} = 3.6V$ ; $V_I = 5.5V$ or GND		±0.1	±5	μΑ	
I <sub>CC</sub>	Quiescent supply current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}; I_O = 0$		0.1	10	μΑ	
$\Delta I_{CC}$	Additional quiescent supply current per input pin	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$ ; $I_O = 0$		5	500	μA	

#### NOTES:

1. All typical values are at V\_{CC} = 3.3V and T\_{amb} = 25°C.

## **AC CHARACTERISTICS**

GND = 0 V;  $t_r = t_f \le 2.5 \text{ ns}$ ;  $C_L = 50 \text{ pF}$ 

						LIMI	rs			
SYMBOL	SYMBOL PARAMETER WAV		V <sub>CC</sub> = 3.3V ±0.3V		V <sub>CC</sub> = 2.7V			$V_{CC} = 1.2V$	UNIT	
			MIN	TYP <sup>1</sup>	MAX	MIN	TYP	MAX	TYP	
t <sub>PHL</sub> / t <sub>PLH</sub>	Propagation delay nA to nY	1	1.5	2.5	4.5	1.5	3.2	5.5	16.0	ns

#### NOTE:

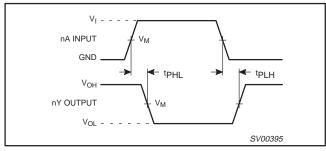
1. These typical values are at V\_{CC} = 3.3V and T\_{amb} = 25°C.

#### AC WAVEFORMS

 $V_{M}$  = 1.5 V at  $V_{CC}\,\geq\,2.7$  V

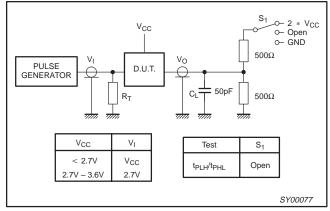
 $V_{\textrm{M}}$  = 0.5 •  $V_{\textrm{CC}}$  at  $V_{\textrm{CC}}$  < 2.7 V

 $V_{\text{OL}}^{\text{in}}$  and  $V_{\text{OH}}$  are the typical output voltage drop that occur with the output load.



Waveform 1. Input (nA) to output (nY) propagation delays.

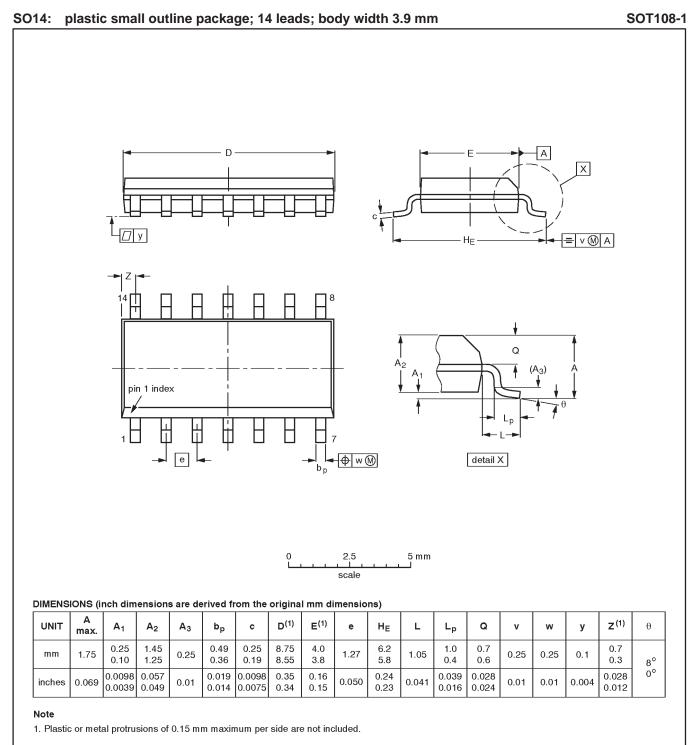
### **TEST CIRCUIT**



Waveform 2. Load circuitry for switching times.

Product specification

## 74LVC04A

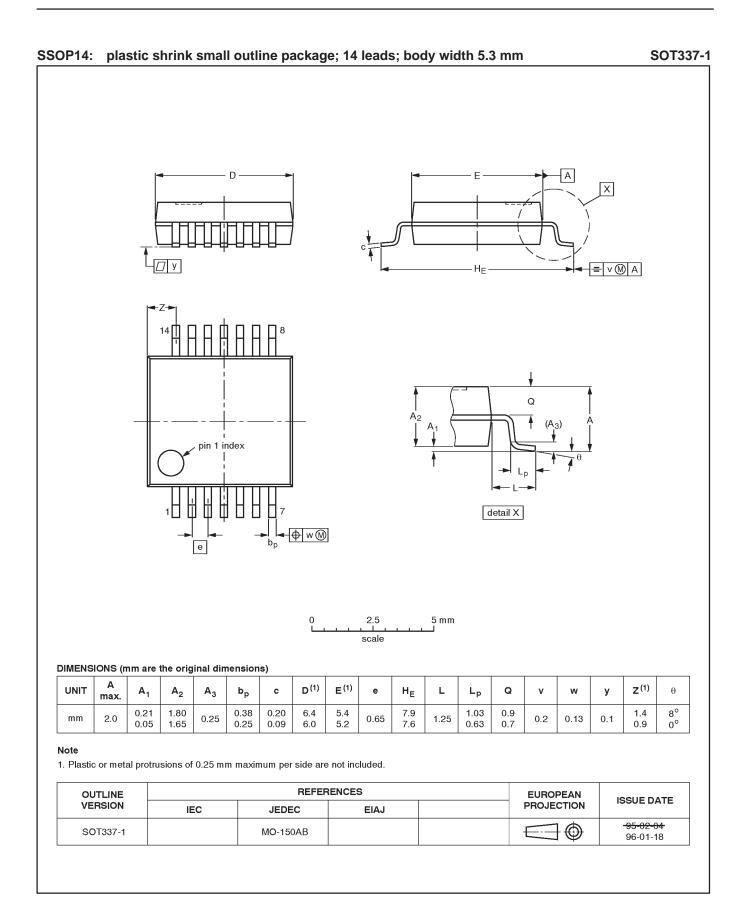


 
OUTLINE VERSION
REFERENCES
EUROPEAN PROJECTION
ISSUE DATE

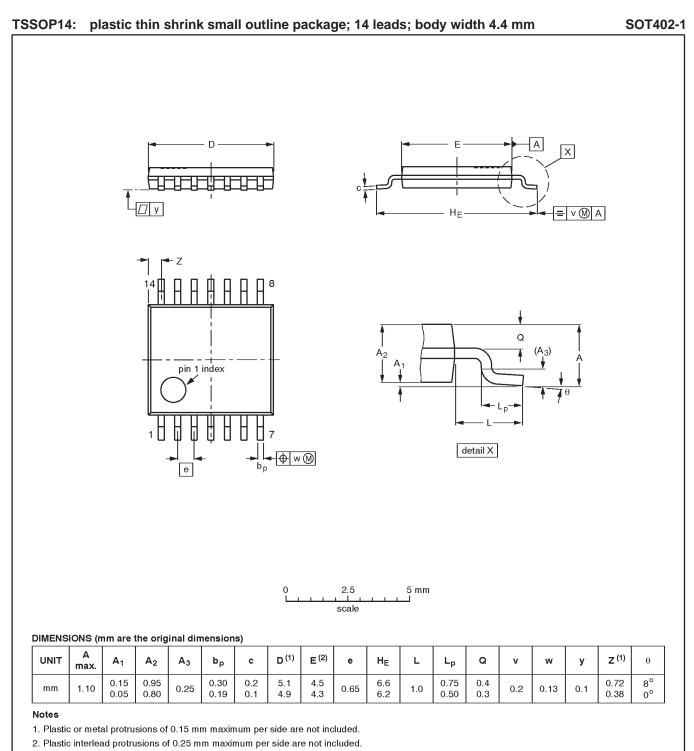
SOT108-1
076E06S
MS-012AB
Image: Constraint of the second secon

#### 1997 Jun 30

## 74LVC04A



## 74LVC04A



OUTLINE		REFER				
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT402-		MO-153				<del>-94-07-12</del> 95-04-04

74LVC04A

NOTES

# 74LVC04A

DEFINITIONS					
Data Sheet Identification	Product Status	Definition			
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.			
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.			
Product Specification Full Production		This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.			

Philips Semiconductors and Philips Electronics North America Corporation reserve the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified. Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

#### LIFE SUPPORT APPLICATIONS

Philips Semiconductors and Philips Electronics North America Corporation Products are not designed for use in life support appliances, devices, or systems where malfunction of a Philips Semiconductors and Philips Electronics North America Corporation Product can reasonably be expected to result in a personal injury. Philips Semiconductors and Philips Electronics North America Corporation customers using or selling Philips Semiconductors and Philips Electronics North America Corporation so at their own risk and agree to fully indemnify Philips Semiconductors and Philips Electronics North America Corporation for any damages resulting from such improper use or sale.

Philips Semiconductors 811 East Arques Avenue P.O. Box 3409 Sunnyvale, California 94088–3409 Telephone 800-234-7381 © Copyright Philips Electronics North America Corporation 1997 All rights reserved. Printed in U.S.A.

print code

Document order number:

Date of release: 05-96 9397-750-04478

Let's make things better.



